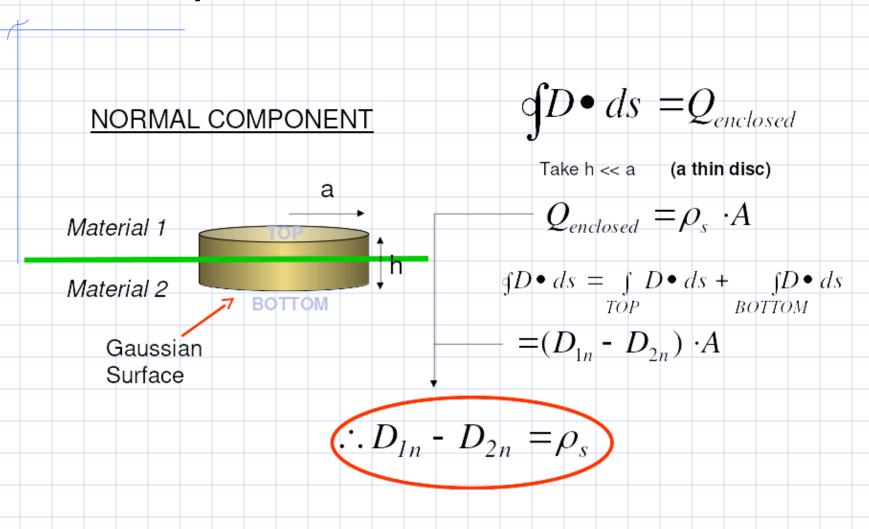
Fields and Waves I

Lecture 14
Laplace + Poisson's Equations
Numerical Methods
Current

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Case 1: REGION 2 is a CONDUCTOR,
$$D_2 = E_2 = 0$$

$$\therefore D_{ln} = \rho_s$$

Material 1

$$\rho_s \neq 0$$

Material 2 conductor

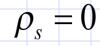
Case 2: REGIONS 1 & 2 are DIELECTRICS with
$$\rho_s = 0$$

Can only really get ρ_s with conductors

$$D_{1n} = D_{2n}$$

$$\therefore \varepsilon_1 E_{1n} = \varepsilon_2 E_{2n}$$

Material 1 dielectric



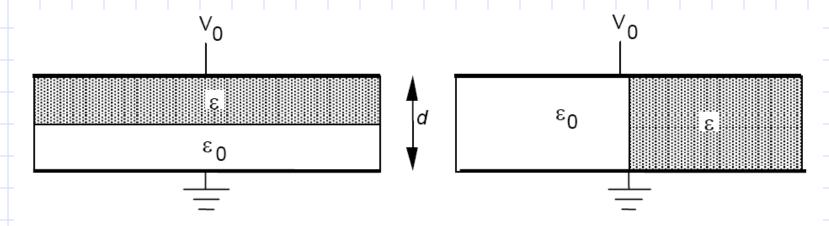
Material 2 dielectric

Consider the two parallel plate geometries below. Assume that the plate dimensions are large compared to the separation d and ignore fringe effects. For the two figures, the electric field in the air region, (specified by ε_0) is given by:

$$\mathbf{E} = -(V_0/d) * (2\varepsilon_r/(1+\varepsilon_r)) \mathbf{a}_z$$

$$E = -(V_0/d) a_z$$

figure on left figure on right



 For both cases, find E in the dielectric region. Find D in both regions. Within a given region, D and E do not vary with position.

Find the charge density on the plates at all locations.

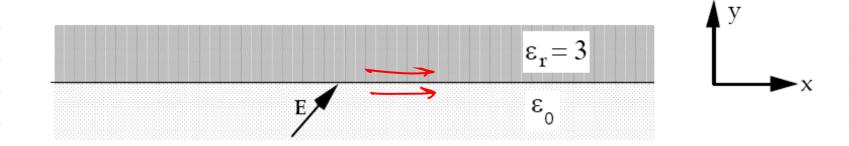
a. Boundary conditions
$$E_{1t} = E_{3t}$$
; $D_{1n} = D_{3n} \Rightarrow E_{3n} = \frac{E_1}{E_3} E_{1n}$
Left: E is normal : $\vec{E}_{diel} = \frac{E_0}{E_7 E_0} E_{air} = \frac{-V_0}{d} \frac{2}{1+E_7} \hat{a}_{\frac{1}{2}}$
Right: E is tangential : $\vec{E}_{diel} = \vec{E}_{air} = \frac{-V_0}{d} a_{\frac{1}{2}}$
 $\vec{D} = E = \frac{Left}{D_{air}} = \frac{V_0}{d} \frac{2E_7 E_0}{1+E_7} \hat{a}_{\frac{1}{2}} = \frac{E_7 E_0 V_0}{d} \hat{a}_{\frac{1}{2}}$
 $\vec{D}_{air} = -\frac{E_0 V_0}{d} \hat{a}_{\frac{1}{2}}$
 $\vec{D}_{air} = -\frac{E_0 V_0}{d} \hat{a}_{\frac{1}{2}}$

b. Boundary conditions at conductor-dielectric
$$D_n = Ps$$

Left: $Ps = \pm \frac{2\epsilon_r \epsilon_o}{1+\epsilon_r} \frac{V_o}{d} + ontop$

on bottom

The **E** field on the air side of a dielectric-dielectric boundary is **E** = $100 \, \mathbf{a}_{x} + 100 \, \mathbf{a}_{y}$. What is **E** on the dielectric side?



$$E_{1x} = E_{2x} \Rightarrow E_{1x} = E_{2x} \Rightarrow \therefore E_{2x} = 100 \qquad \text{Air} = \text{Region 1}$$

$$D_{1n} = D_{2n} \Rightarrow \varepsilon_0 E_{1y} = 3\varepsilon_0 E_{2y} \Rightarrow E_{2y} = \frac{E_{1y}}{3} = \frac{100}{3} = 33\frac{1}{3}$$

$$\overline{E}_2 = 100 \hat{a}_x + 33\frac{1}{3} \hat{a}_y$$

Integral Form

Differential Form

$$\oint \vec{D} \cdot \vec{ds} = \int \rho \cdot dv$$

$$abla \cdot \vec{D} =
ho$$

$$\oint \vec{E} \cdot d\vec{l} = 0$$

$$\nabla \times \vec{E} = 0$$

What if we try to rewrite Maxwell's Equations in terms of voltage?

$$\vec{E} = -\nabla V$$

First, the curl equation

$$\vec{E} = -\nabla V \Rightarrow \nabla \times \vec{E} = 0$$

$$\text{since } \nabla \times (\nabla f) = 0$$

Next, the divergence equation

Laplacian of V = divergence of gradient of V Fields and Waves I

Laplace's Equation:

$$\nabla^2 V = 0$$

Poisson's Equation

$$\nabla^2 V = -\frac{\rho}{\varepsilon}$$

$$\nabla^{2} = \begin{bmatrix} \frac{\partial V}{\partial x} & \frac{\partial V}{\partial y} & \frac{\partial V}{\partial z} \end{bmatrix} \bullet \begin{bmatrix} \frac{\partial}{\partial x} \\ \frac{\partial}{\partial y} \\ \frac{\partial}{\partial z} \end{bmatrix} = \frac{\partial^{2}V}{\partial x^{2}} + \frac{\partial^{2}V}{\partial y^{2}} + \frac{\partial^{2}V}{\partial z^{2}}$$
(in cartesian coordinates)

Cylindrical Laplacian Operator:

$$\nabla^2 V = \frac{1}{r} \frac{\partial}{\partial r} (r \frac{\partial V}{\partial r}) + \frac{1}{r^2} \frac{\partial^2 V}{\partial \phi^2} + \frac{\partial^2 V}{\partial z^2}$$

Spherical Laplacian Operator:

$$\nabla^2 V = \frac{1}{r^2} \frac{\partial}{\partial r} (r^2 \frac{\partial V}{\partial r}) + \frac{1}{r^2 sin\theta} \frac{\partial}{\partial \theta} (sin\theta \frac{\partial V}{\partial \theta}) + \frac{1}{r^2 sin^2 \theta} \frac{\partial^2 V}{\partial \phi^2}$$

- Laplace's Equation and Poisson's Equation are general mathematical expressions that allow us to solve scalar fields if we know the boundary conditions. They are used for solving for:
 - Voltage
 - Heat
 - Gravity
 - Aspects of fluid flow
 - Various abstract mathematical fields
 - etc.

Boundary Conditions

In General

$$D_{n_1} - D_{n_2} = \rho_s \quad E_{t_1} = E_{t_2}$$

Dielectric-Dielectric

$$D_{n1} = D_{n2}$$
 $E_{t1} = E_{t2}$

Conductor-Dielectric

$$D_{n1} = \rho_s \qquad E_{t1} = 0$$

Boundary Conditions

Dielectric-Dielectric

$$D_{n1} = D_{n2} - E_{t1} = E_{t2}$$

Writing in terms of voltage:

$$\varepsilon_{1} \frac{\partial V_{1}}{\partial n} = \varepsilon_{2} \frac{\partial V_{2}}{\partial n} \qquad V_{1} = V_{2}$$

here, n represents direction of boundary normal

Fields and Waves I

Boundary Conditions

Dielectric-Dielectric

$$D_{n1} = D_{n2}$$

$$E_{t1} = E_{t2}$$

Writing in terms of voltage:

$$\varepsilon_1 \frac{\partial V_1}{\partial n} = \varepsilon_2 \frac{\partial V_2}{\partial n}$$

$$V_1 = V_2$$

this limit ensures voltage continuity

Fields and Waves I

Boundary Conditions

Conductor-Dielectric

$$D_{n1} = \rho_s$$

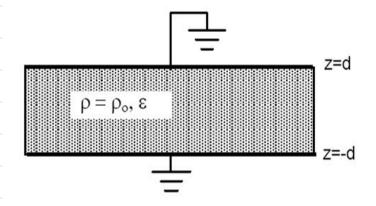
$$E_{t1} = 0$$

$$\frac{\partial V_1}{\partial n} = \rho_s$$

$$V_1 = const$$

- Coulomb's Law is already a solution
- All other voltage expressions can be checked with one of these equations
- This is the most common way of finding electric fields

A charged region of a semiconductor is sandwiched between two grounded conductors as shown below.



Solve for V(z) directly using Poisson's Equation

Find **E** and **D**

Find the charge density on the conductors

a.
$$\nabla^2 V = - \int_E \Rightarrow \forall k V = V(z)$$
, $\nabla^2 V = \frac{d^2 V}{dz^2}$

$$\frac{dV}{dz} = -\frac{pz}{E} + C_1 \Rightarrow \dots = \frac{pz^2}{2E} + C_1 z + C_2$$

$$V(d) = 0 = -\frac{pd^2}{2E} + C_1 d + C_2 \qquad Add = 0 = \frac{pd^2}{2E} + 3C_2 = 0$$

$$V(-d) = 0 = -\frac{pd^2}{2E} - C_1 d + C_2 \qquad \text{Subtract eq.} \qquad 2c_1 d = 0 \Rightarrow c_1 = 0$$

$$V = -\frac{pz^2}{2E} + \frac{pd^2}{2E} = \frac{p}{2E} (d^2 - z^2)$$

$$D = E = -\nabla V = -\frac{\partial V}{\partial z} \hat{a}_z = -\frac{p}{2E} (-2z) \hat{a}_z = \frac{pz}{E} \hat{a}_z$$

$$C. \text{ Boundary condition } D_n = P_S$$
if $P_S > 0$ D points into surface $z = 0$ both $z = 0$ $z = 0$

$$P_S = -pd \text{ on both}$$

A coaxial cable has an inner conductor (at r = a) held at voltage V_0 and an outer conductor (at r = b) that is grounded. There is no charge other than the surface charge on the conductors.

Solve for V(r) directly using Laplace's Equation

Solve for **E** and **D**

What is the charge density on the two conductors?

What is the capacitance per unit length?

0.
$$\nabla^{2}V = 0$$
 $V = V(r) \Rightarrow : \nabla^{2}V = \frac{1}{r} \frac{d}{dr} (r \frac{dV}{dr}) = 0$

$$\frac{d}{dr} (r \frac{dV}{dr}) = 0 \Rightarrow r \frac{dV}{dr} = c_{1}; \quad \frac{dV}{dr} = c_{1} \Rightarrow V = c_{1} \frac{dr}{dr} + c_{2}$$

$$V(b) = 0 = c_{1} \frac{dr}{dr} + c_{2} \Rightarrow c_{2} = -c_{1} \frac{dr}{dr} \Rightarrow V = c_{1} \frac{dr}{dr} = c_{1} \frac{dr}{dr} + c_{2} \frac{dr}{dr} = c_{1} \frac{dr}{dr} = c_{1} \frac{dr}{dr} + c_{2} \frac{dr}{dr} + c_{2} \frac{dr}{dr} = c_{1} \frac{dr}{dr} + c_{2} \frac{dr}{dr} + c_{2} \frac{dr}{dr} = c_{1} \frac{dr}{dr} + c_{2} \frac{dr}{dr} + c_{2} \frac{dr}{dr} = c_{1} \frac{dr}{dr} +$$

$$b. \vec{E} = -\nabla V = -\frac{\partial V}{\partial r} \hat{a}_r = -\frac{V_o}{h b'_a} \frac{1}{b / r} \left(-\frac{b}{r s} \right) \hat{a}_r = \frac{V_o}{r h b'_a} \hat{a}_r$$

$$\vec{D} = \varepsilon \vec{E} = \frac{\varepsilon V_o}{r h b'_a} \hat{a}_r$$

- ...but as engineers, you all know that integrals can be very difficult to evaluate for all but very simple geometries.
- So how do we solve for V(r) when the geometry is more complex?
- We rely on numerical methods
 - Finite Difference
 - Finite Elements
 - Method of Moments
 - Etc.

Review

Laplace's Equation:

$$\nabla^2 V = 0$$

Poisson's Equation

$$\nabla^2 V = -\frac{\rho}{\varepsilon}$$

$$\nabla^{2} = \begin{bmatrix} \frac{\partial V}{\partial x} & \frac{\partial V}{\partial y} & \frac{\partial V}{\partial z} \end{bmatrix} \bullet \begin{bmatrix} \frac{\partial}{\partial x} \\ \frac{\partial}{\partial y} \end{bmatrix} = \frac{\partial^{2}V}{\partial x^{2}} + \frac{\partial^{2}V}{\partial y^{2}} + \frac{\partial^{2}V}{\partial z^{2}}$$
(in cartesian coordinates)

Fields and Waves I

Boundary Conditions

Dielectric-Dielectric

$$D_{n1} = D_{n2} - E_{t1} = E_{t2}$$

Writing in terms of voltage:

$$\varepsilon_{1} \frac{\partial V_{1}}{\partial n} = \varepsilon_{2} \frac{\partial V_{2}}{\partial n} \qquad V_{1} = V_{2}$$

this limit ensures voltage continuity

Fields and Waves I

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Boundary Conditions

Conductor-Dielectric

$$D_{n1} = \rho_s$$

$$E_{t1} = 0$$

$$\frac{\partial V_1}{\partial n} = \rho_s$$

$$V_1 = const$$

Cylindrical Laplacian Operator:

$$\nabla^2 V = \frac{1}{r} \frac{\partial}{\partial r} (r \frac{\partial V}{\partial r}) + \frac{1}{r^2} \frac{\partial^2 V}{\partial \phi^2} + \frac{\partial^2 V}{\partial z^2}$$

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Solve for V(r) directly using Laplace's Equation

Solve for **E** and **D**

What is the charge density on the two conductors?

What is the capacitance per unit length?

0.
$$\nabla^{2}V = 0$$
 $V = V(r) \Rightarrow : \nabla^{2}V = + \frac{d}{dr}(r\frac{dV}{dr}) = 0$

$$\frac{d}{dr}(r\frac{dr}{dr}) = 0 \Rightarrow r\frac{dr}{dr} = c_{1}; \quad \frac{dV}{dr} = \frac{c_{1}}{r}; \quad \frac{dV}{dr} = \frac{c_{1}}{r} = \frac{d}{dr}(r\frac{dV}{dr}) = 0$$

$$V(b) = 0 = c_{1} \ln b + c_{2} \Rightarrow c_{2} = -c_{1} \ln b \Rightarrow V = c_{1} \ln \frac{r}{b}$$

$$V(a) = V_{0} = c_{1} \ln \frac{a}{b} \Rightarrow c_{1} = \frac{V_{0}}{L_{0}} \Rightarrow V = \frac{V_{0}}{L_{0}} \ln \frac{r}{b}$$

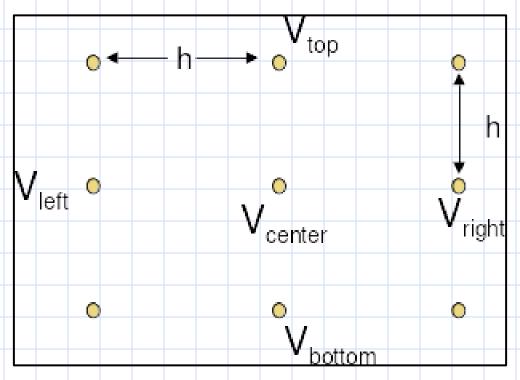
$$b. \vec{E} = -\nabla V = -\frac{\partial V}{\partial r} \hat{a}_r = -\frac{V_o}{h b'_a} \frac{1}{b'_r} \left(-\frac{b}{r}_s \right) \hat{a}_r = \frac{V_o}{r h b'_a} \hat{a}_r$$

$$\vec{D} = \varepsilon \vec{E} = \frac{\varepsilon V_o}{r h b'_a} \hat{a}_r$$

- ...but as engineers, you all know that integrals can be very difficult to evaluate for all but very simple geometries.
- So how do we solve for V(r) when the geometry is more complex?
- We rely on numerical methods
 - Finite Difference
 - Finite Elements
 - Method of Moments
 - Etc.
- Generally, these methods break the problem into discrete pieces and linearize it while utilizing boundarys conditions.

Finite Difference Method

Consider a grid of points in a voltage field with distance h between them.



 V_{center} is at the origin (0,0).

Finite Difference Method

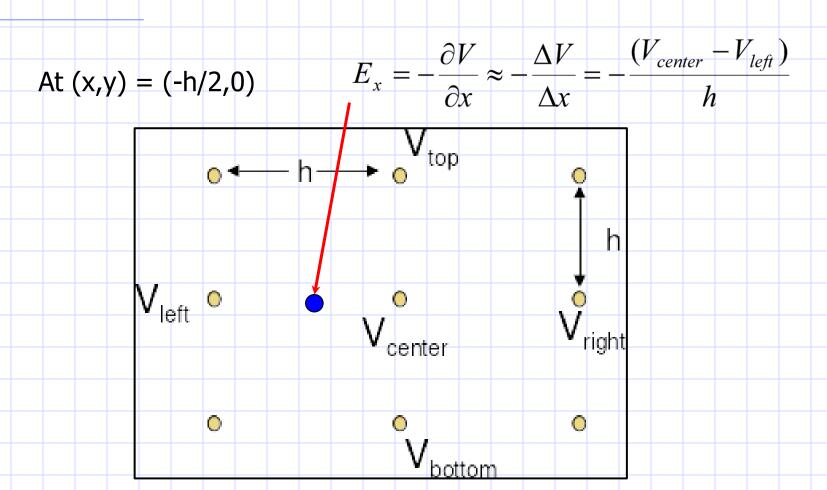
At
$$(x,y) = (h/2,0)$$

$$E_{x} = -\frac{\partial V}{\partial x} \approx -\frac{\Delta V}{\Delta x} = -\frac{(V_{right} - V_{center})}{h}$$

$$V_{left} \qquad V_{center}$$

The E-field can be approximated by taking the difference of the two adjacent voltages.

Finite Difference Method



The E-field can be approximated by taking the difference of the two adjacent voltages.

Finite Difference Method

$$\nabla^{2}V = \nabla \bullet \nabla V = -\nabla \bullet E = -\frac{\partial E_{x}}{\partial x} - \frac{\partial E_{y}}{\partial y} - \frac{\partial E_{z}}{\partial z}$$
 (no z contribution in this case)

To find the x-direction contribution to the E-field at V_{center}:

$$\frac{\partial E_x}{\partial x} \approx \frac{\Delta E_x}{\Delta x} = \frac{E_x \left(\frac{h}{2}, 0\right) - E_x \left(-\frac{h}{2}, 0\right)}{h} = \frac{2 \cdot V_{center} - V_{right} - V_{left}}{h^2}$$

We can find a similar expression for the y-direction contribution:

$$\frac{\partial \vec{E}_y}{\partial y} \approx \frac{\Delta \vec{E}_y}{\Delta y} = \frac{2 \cdot V_{center} - V_{top} - V_{bottom}}{h^2}$$

Laplace and Poisson Equations

Finite Difference Method

Finally we obtain the following expression:

$$\nabla^{2}V = \frac{4 \cdot V_{center} - (V_{right} + V_{left} + V_{top} + V_{bottom})}{h^{2}} = -\frac{\rho}{\varepsilon}$$

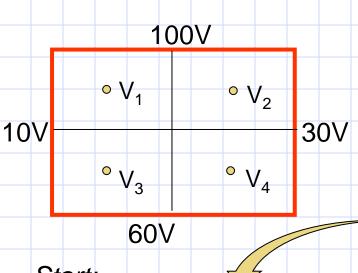
Rearrange the equation to solve for V_{center}

 $V_{center} = \frac{1}{4} \cdot \left(\sum V_{neighbors} - \frac{\rho \cdot h^2}{\varepsilon} \right)$ Poisson Equation Solver

$$V_{center} = \frac{1}{4} \cdot \left(\sum V_{neighbors}\right)$$
Laplace Equation
Solver

Laplace and Poisson Equations

Finite Difference Method



Solution Technique - by Iteration

Guess a solution: V=0 everywhere except boundaries

$$V_1 = V_2 = V_3 = V_4 = 0$$

Start:

$$V_{1} = \frac{1}{4} \cdot (100 + 10 + V_{2} + V_{3}) \longrightarrow V_{1} = \frac{1}{4} \cdot (110 + 0) = 27.5$$

$$V_{2} = \frac{1}{4} \cdot (100 + 30 + V_{1} + V_{4}) \longrightarrow V_{2} = \frac{1}{4} \cdot (130 + 27.5 + 0) = 39.375$$

$$V_{3} = \frac{1}{4} \cdot (10 + 60 + V_{1} + V_{4}) \longrightarrow V_{3} = \frac{1}{4} \cdot (70 + 27.5 + 0) = 24.375$$

$$V_{4} = \frac{1}{4} \cdot (30 + 60 + V_{2} + V_{3}) \longrightarrow V_{4} = \frac{1}{4} \cdot (90 + 39.375 + 24.375) = 38.4375$$

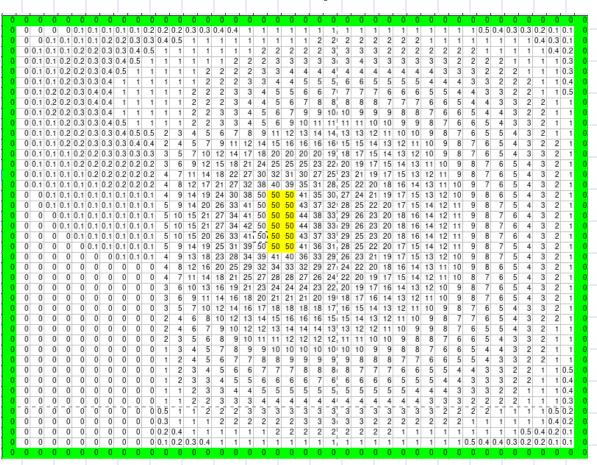
Put new values back

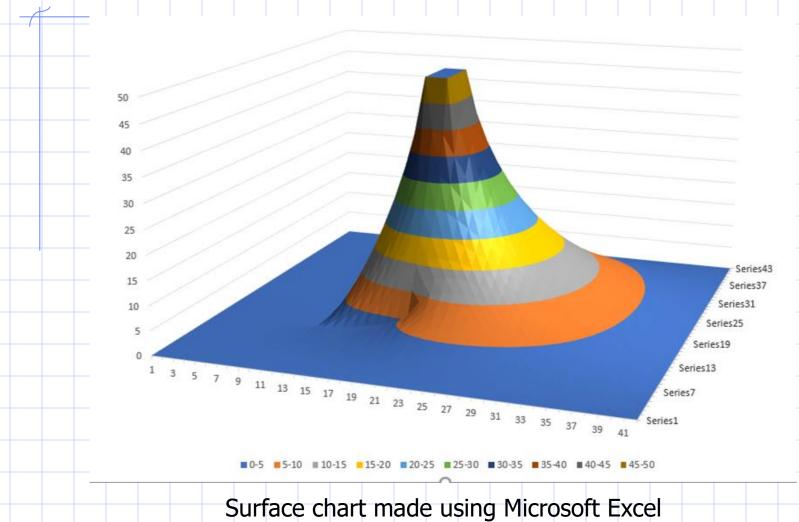
Laplace and Poisson Equations

Finite Difference Method

Do Lecture 13, Exercise 1 in groups of up to 4.

The Finite Difference method can be done in a spreadsheet (the next Studio Session will be based on this)





Suppose that this represents a conductive rectangle held at 50V.

$$E_x = -\frac{\partial V}{\partial x} \approx -\frac{\Delta V}{\Delta x}$$

-	Щ.				_	_	-	_		-	_	_	_	-			_	-	Щ,	4		
i	1	1	1	1	2	2	3	3	4	5	6	7	9	9	10ı	10	9	9	3	8	8	7
5	1	1	1	1	2	2	3	3	4	5	6	9	10	11	11	11	11	10	10	9	9	8
ŀ	0.5	0.5	2	3	4	5	6	7	8	9	11	12	13	14	14	13	13	12	11	10	10	9
8	0.4	0.4	2	4	5	7	9	11	12	14	15	16	16	16	161	15	13	14	13	12	11	10
8	0.3	0.3	3	5	7	10	12	14	17	18	20	20	20	20	19	18	17	15	14	13	12	10
2	0.2	0.2	3	6	9	12	15	18	21	24	25	25	25	23	22	20	19	17	15	14	13	11
2	0.2	0.2	4	7	11	14	18	22	27	30	32	31	30	27	25	23	21	19	17	15	13	12
2	0.2	0.2	4	8	12	17	21	27	32	38	40	39	35	31	28	25	22	20	18	16	14	13
	0.1	0.1	4	9	14	19	24	30	38	50	50	50	41	35	30	27	24	21	19	17	15	13
I	0.1	0.1	5	9	14	20	26	33	41	50	50	50	43	37	321	28	25	22	20	17	15	14
П	0.1	0.1	5	10	15	21	27	34	41	50	50	50	44	38	33	29	26	23	20	18	16	14
ı	0.1	0.1	5	10	15	21	27	34	42	50	50	50	44	38	331	29	26	23	20	18	16	14
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ı	0.1	0.1	5	9	14	19	25	31	39	50	50	50	41	36	31	28	25	22	20	17	15	14
	0.1	0.1	4	9	13	18	23	28	34	39	41	40	36	33	29	26	23	21	19	17	15	13
)	0	0	4	8	12	16	20	25	29	32	34	33	32	29	271	24	22	20	18	16	14	13
)	0	0	4	7	11	14	18	21	25	27	28	28	27	26	24	22	20	19	17	15	14	12
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)	0	0	3	6	9	11	14	16	18	20	21	21	21	20	19!	18	17	16	14	13	12	11
)	0	0	3	5	7	10	12	14	16	17	18	18	18	18	17	16	15	14	13	12	11	10
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)	0	0	2	4	6	7	9	10	12	12	13	14	14	14	13 ¹	13	12	12	11	10	9	9

Suppose that this represents a conductive rectangle held at 50V.

 $D_x = \epsilon_0 E_x$

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i	1	1	1	1	2	2	3	3	4	5	6	7	9	9	10:1	10	9	9	3	8	8	7
5	1	1	1	1	2	2	3	3	4	5	6	9	10	11	11, 1	11	11	10	10	9	9	8
ŧ	0.5	0.5	2	3	4	5	6	7	8	9	11	12	13	14	14, 1	13	13	12	11	10	10	9
8	0.4	0.4	2	4	5	7	9	11	12	14	15	16	16	16	1611	15	13	14	13	12	11	10
8	0.3	0.3	3	5	7	10	12	14	17	18	20	20	20	20	19, 1	18	17	15	14	13	12	10
2	0.2	0.2	3	6	9	12	15	18	21	24	25	25	25	23	221	20	19	17	15	14	13	11
2	0.2	0.2	4	7	11	14	18	22	27	30	32	31	30	27	25 2	23	21	19	17	15	13	12
2	0.2	0.2	4	8	12	17	21	27	32	38	40	39	35	31	28, 2	25	22	20	18	16	14	13
П	0.1	0.1	4	9	14	19	24	30	38	50	50	50	41	35	30, 2	27	24	21	19	17	15	13
П	0.1	0.1	5	9	14	20	26	33	41	50	50	50	43	37	321 2	28	25	22	20	17	15	14
П	0.1	0.1	5	10	15	21	27	34	41	50	50	50	44	38	33, 2	29	26	23	20	18	16	14
Ī	0.1	0.1	5	10	15	21	27	34	42	50	50	50	44	38	331 2	29	26	23	20	18	16	14
П	0.1	0.1	5	10	15	20	26	33	41	50	50	50	43	37	33 2	29	25	23	20	18	16	14
Ī	0.1	0.1	5	9	14	19	25	31	39	50	50	50	41	36	31, 2	28	25	22	20	17	15	14
П	0.1	0.1	4	9	13	18	23	28	34	39	41	40	36	33	29, 2	26	23	21	19	17	15	13
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)	0	0	3	6	9	11	14	16	18	20	21	21	21	20	1911	18	17	16	14	13	12	11
)	0	0	3	5	7	10	12	14	16	17	18	18	18	18	17, 1	16	15	14	13	12	11	10
)	0	0	2	4	6	8	10	12	13	14	15	16	16	16	15: 1	15	14	13	12	11	10	9
)	0	0	2	4	6	7	9	10	12	12	13	14	14	14	131 1	13	12	12	11	10	9	9

Suppose that this represents a conductive rectangle held at 50V.

 $D_x = \rho$

	_	_					-				_	_						_		_		
Ħ	1	1	1	1	2	2	3	3	4	5	6	7	9	9	10	10	9	9	3	8	8	7
5	1	1	1	1	2	2	3	3	4	5	6	9	10	11	11	11	11	10	10	9	9	8
F	0.5	0.5	2	3	4	5	6	7	8	9	11	12	13	14	14	13	13	12	11	10	10	9
8	0.4	0.4	2	4	5	7	9	11	12	14	15	16	16	16	161	15	15	14	13	12	11	10
8	0.3	0.3	3	5	7	10	12	14	17	18	20	20	20	20	19	18	17	15	14	13	12	10
2	0.2	0.2	3	6	9	12	15	18	21	24	25	25	25	23	22	20	19	17	15	14	13	11
2	0.2	0.2	4	7	11	14	18	22	27	30	32	31	30	27	25	23	21	19	17	15	13	12
2	0.2	0.2	4	8	12	17	21	27	32	38	40	39	35	31	28	25	22	20	18	16	14	13
П	0.1	0.1	4	9	14	19	24	30	38	50	50	50	41	35	30	27	24	21	19	17	15	13
П	0.1	0.1	5	9	14	20	26	33	41	50	50	50	43	37	321	28	25	22	20	17	15	14
П	0.1	0.1	5	10	15	21	27	34	41	50	50	50	44	38	33	29	26	23	20	18	16	14
П	0.1	0.1	5	10	15	21	27	34	42	50	50	50	44	38	331	29	26	23	20	18	16	14
П	0.1	0.1	5	10	15	20	26	33	41	50	50	50	43	37	33	29	25	23	20	18	16	14
П	0.1	0.1	5	9	14	19	25	31	39	50	50	50	41	36	31	28	25	22	20	17	15	14
П	0.1	0.1	4	9	13	18	23	28	34	39	41	40	36	33	29	26	23	21	19	17	15	13
)	0	0	4	8	12	16	20	25	29	32	34	33	32	29	271	24	22	20	18	16	14	13
)	0	0	4	7	11	14	18	21	25	27	28	28	27	26	24	22	20	19	17	15	14	12
)	0	0	3	6	10	13	16	19	21	23	24	24	24	23	22	20	19	17	16	14	13	12
)	0	0	3	6	9	11	14	16	18	20	21	21	21	20	191	18	17	16	14	13	12	11
)	0	0	3	5	7	10	12	14	16	17	18	18	18	18	17	16	15	14	13	12	11	10
)	0	0	2	4	6	8	10	12	13	14	15	16	16	16	151	15	14	13	12	11	10	9
) [0	0	2	4	6	7	9	10	12	12	13	14	14	14	13 ¹	13	12	12	11	10	9	9

You now know the charge density on this surface of this cell of the conductor. You can do the same for adjacent cells.

f

_																						
i	1	1	1	1	2	2	3	3	4	5	6	7	9	9	10	10	9	9	3	8	8	7
5	- 1	1	1	- 1	2	2	3	3	4	5	6	9	10	11	11	11	11	10	10	9	9	8
ŀ	0.5	0.5	2	3	4	5	6	7	8	9	11	12	13	14	14	13	13	/12	11	10	10	9
8	0.4	0.4	2	4	5	7	9	11	12	14	15	16	16	16	161	15	15	14	13	12	11	10
8	0.3	0.3	3	5	7	10	12	14	17	18	20	20	20	20	19	18	17	15	14	13	12	10
2	0.2	0.2	3	6	9	12	15	18	21	24	25	25	25	23	22	20	19	17	15	14	13	11
2	0.2	0.2	4	7	11	14	18	22	27	30	32	31	30	27	25	23	21	19	17	15	13	12
2	0.2	0.2	4	8	12	17	21	27	32	38	40	39	35	31	28	25	22	20	18	16	14	13
	0.1	0.1	4	9	14	19	24	30	38	50	50	50	41	35	30	27	24	21	19	17	15	13
	0.1	0.1	5	9	14	20	26	33	41	50	50	50	43	37	32	28	25	22	20	17	15	14
	0.1	0.1	5	10	15	21	27	34	41	50	50	50	44	38	33	29	26	23	20	18	16	14
	0.1	0.1	5	10	15	21	27	34	42	50	50	50	44	38	331	29	26	23	20	18	16	14
	0.1	0.1	5	10	15	20	26	33	41		50	50	43	37	33		25	23	20	18	16	14
ı	0.1	0.1	5	9	14	19	25	31	39	50	50	50	41	36	31	28	25	22	20	17	15	14
	0.1	0.1	4	9	13	18	23	28	34	39	41	40	36	33		26	23	21	19	17	15	13
)	0	0	4	8	12	16	20	25	29	32	34	33	32	29	271	24	22	20	18	16	14	13
)	0	0	4	7	11	14	18	21	25	27	28	28	27	26	_	22	20	19	17	15	14	12
)	0	0	3	6	10	13	16	19	21	23	24	24	24	23	22	20	19	17	16	14	13	12
)	0	0	3	6	9	11	14	16	18	20	21	21	21	20	19	18	17	16	14	13	12	11
)	0	0	3	5	7	10	12	14	16	17	18	18	18	18	17	16	15	14	13	12	11	10
)	0	0	2	4	6	8	10	12	13	14	15	16	16	16	15:	15	14	13	12	11	10	9
)	0	0	2	4	6	7	9	10	12	12	13	14	14	14	13 ¹	13	12	12	11	10	9	9

You can then multiply the charge density on each of the cell surfaces below by its area to get the total charge on the right side of the conductor.

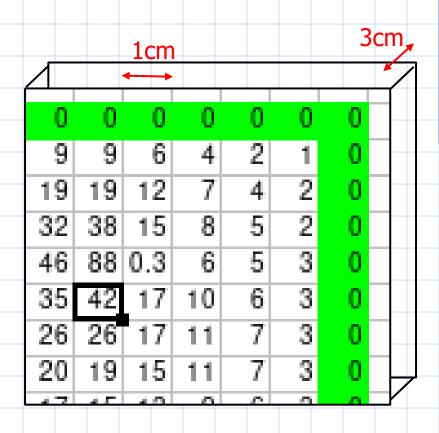
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How do you determine the area of this side of the conductor?

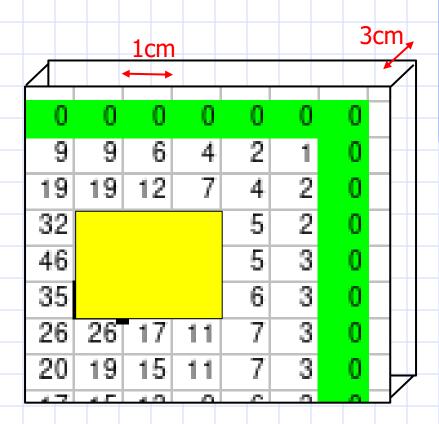
_		_			_	_	_							_		_	_	_			_	
	1	1	1	1	2	2	3	3	4	5	6	7	9	9	10	10	9	9	3	8	8	7
5	1	1	1	1	2	2	3	3	4	5	6	9	10	11	11	11	11	10	10	9	9	8
0	.5	0.5	2	3	4	5	6	7	8	9	11	12	13	14	14	13	13	12	11	10	10	9
8 0	.4	0.4	2	4	5	7	9	11	12	14	15	16	16	16	16	15	15	14	13	12	11	10
8 0	.3	0.3	3	5	7	10	12	14	17	18	20	20	20	20	19	18	17	15	14	13	12	10
0	.2	0.2	3	6	9	12	15	18	21	24	25	25	25	23	22	20	19	17	15	14	13	11
0	.2	0.2	4	7	11	14	18	22	27	30	32	31	30	27	25	23	21	19	17	15	13	12
0	.2	0.2	4	8	12	17	21	27	32	38	40	39	35	31	28	25	22	20	18	16	14	13
0	.1	0.1	4	9	14	19	24	30	38	50	50	50	41	35	30		24	21	19	17	15	13
0	.1	0.1	5	9	14	20	26	33	41	50	50	50	43	37	32	28	25	22	20	17	15	14
0	.1	0.1	5	10	15	21	27	34	41	50	50	50	44	38	33	29	26	23	20	18	16	14
0	.1	0.1	5	10	15	21	27	34	42	50	50	50	44	38	331	29	26	23	20	18	16	14
0	.1	0.1	5	10	15	20	26	33	41	50	50	50	43	37	33	29	25	23	20	18	16	14
0	.1	0.1	5	9	14	19	25	31	39	50	50	50	41	36	31	28	25	22	20	17	15	14
0	.1	0.1	4	9	13	18	23	28	34	39	41	40	36	33	29	26	23	21	19	17	15	13
)	0	0	4	8	12	16	20	25	29	32	34	33	32	29	27	24	22	20	18	16	14	13
)	0	0	4	7	11	14	18	21	25	27	28	28	27	26	24	22	20	19	17	15	14	12
)	0	0	3	6	10	13	16	19	21	23	24	24	24	23	22	20	19	17	16	14	13	12
)	0	0	3	6	9	11	14	16	18	20	21	21	21	20	19		17	16	14	13	12	11
)	0	0	3	5	7	10	12	14	16	17	18	18	18	18	17	16	15	14	13	12	11	10
)	0	0	2	4	6	8	10	12	13	14	15	16	16	16	15	15	14	13	12	11	10	9
	0	0	2	4	6	7	9	10	12	12	13	14	14	14	13 ¹	13	12	12	11	10	9	9

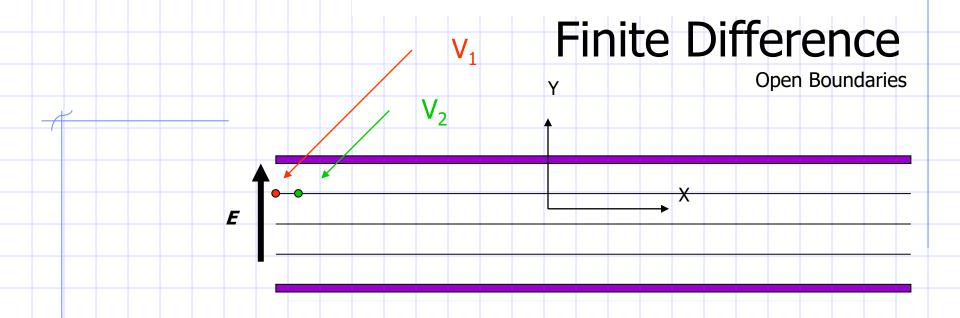
- To calculate real quantities other than voltage, you must assign some dimension to each cell
- To represent true three-dimensional problem, each cell must also represent some depth (or represent per per per and Waves I

length or depth)



 What is the area of the surfaces of this region parallel to the spreadsheet plane?





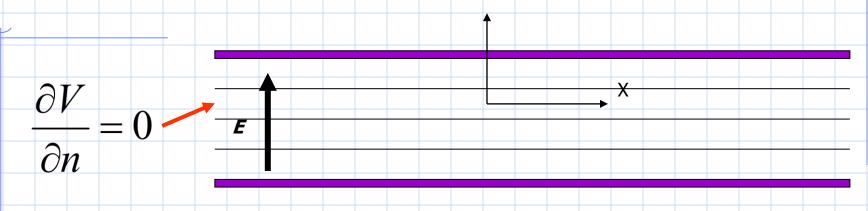
- For a parallel plate capacitor the side boundaries are open and the equipotentials are horizontal.
- For such voltage lines, the boundary voltage will equal the value of its immediate inside neighbor.

$$E_x = -\frac{\partial V}{\partial x} = 0$$

$$\therefore V_1 = V_2$$

$$\therefore V_1 = V_2$$

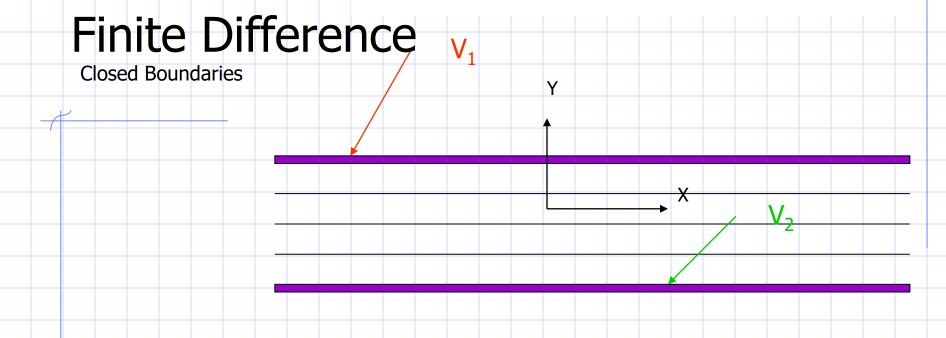
Open Boundaries



 Note that the condition that two points are on the same equipotential is the same as

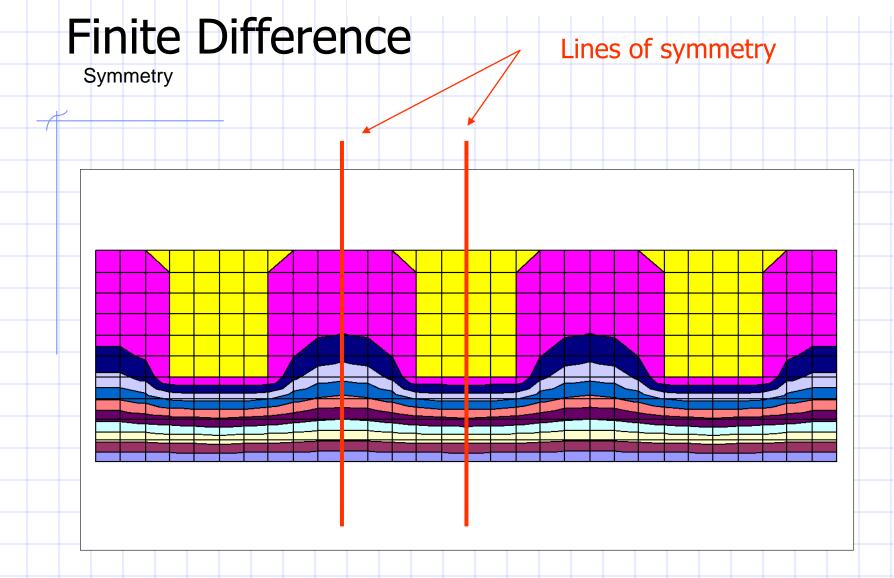
$$D \bullet n = 0 \Leftrightarrow \hat{a}_x \bullet \varepsilon \nabla V = 0$$
 written as $\frac{\partial V}{\partial n} = 0$

 This type of BC is called a Uniform Neumann Boundary Condition (from Mathematics).



 For completeness, we should also note that any part of the boundary that is given a fixed voltage has what is called a Dirichlet Boundary Condition

- For a unique solution
 - At least one Dirichlet needs to be specified



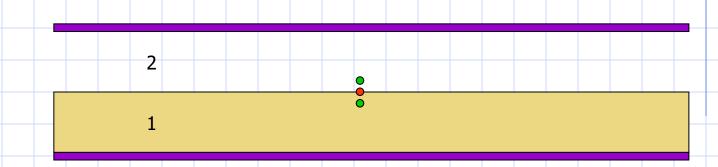
 We can greatly reduce the work to find numerical solutions by using symmetry.

 At a dielectric-dielectric boundary, the voltage is continuous, but the normal derivative is not. (Rate of change of voltage can be different.)

$$D_{n1} = D_{n2}$$

• What does this means in terms of potential ?

Dielectric Boundary



If there are two dielectrics, then the boundary condition at the interface must satisfy the diel-diel BC $D_{n,1} = D_{n,2}$

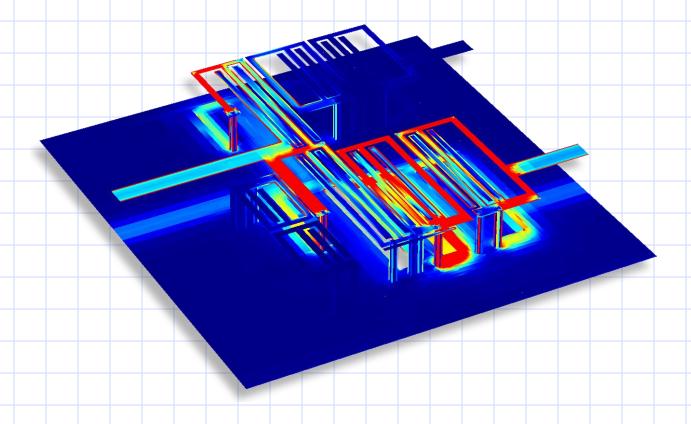
$$\frac{V - V}{\varepsilon_1} = \varepsilon_2 - V - V + \varepsilon_2 V_{up} + \varepsilon_2 V_{up} + \varepsilon_2 V_{up} + \varepsilon_2 V_{up} + \varepsilon_2 V_{up}$$

Fields and Waves I

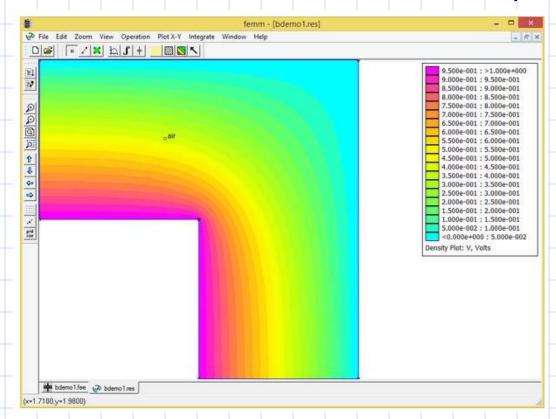
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- <u>Finite Difference</u>: generally breaks a field region into a square grid
- Finite Element: can break a field region into subdivisions of any geometry

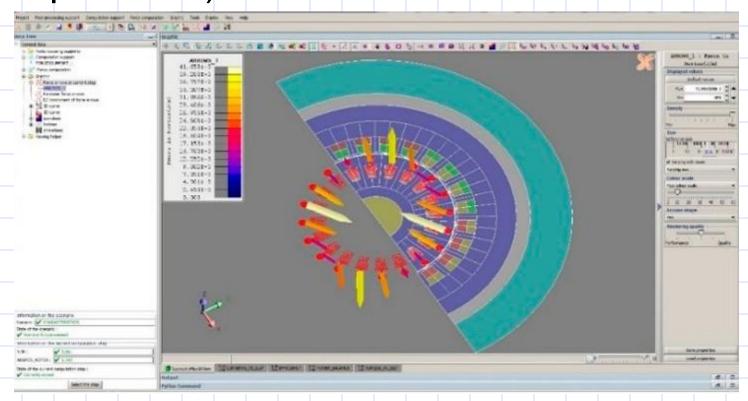
Sonnet (used for analog and digital circuit design applications)



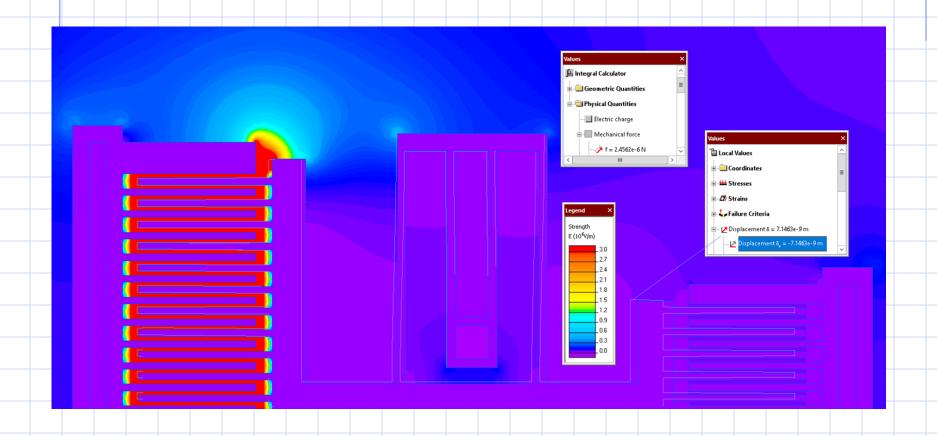
FEMM (open source, designed for magnetics but can be used for electrostatics)



Altair Flux (wide range of electromagnetic capabilities)

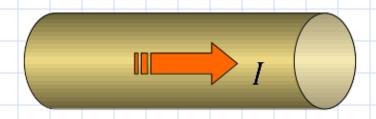


QuickField



- We have been considering electrostatics the case in which there are no moving charges.
- This obviously doesn't hold in general. When charges move, we have current.
- We will consider two parameters: current (measured in amps), and current density (measured in amps per unit area)

Wire with current, I



In general,

$$I = \int j \bullet ds$$

Flux Integral

Definition:
$$I = \frac{\Delta Q}{\Delta t}$$

Charge passing through cross-section in time Δt

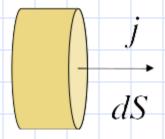
Define:
$$j = \frac{I}{Area} \hat{a}_z$$
cross-section

points in direction of current flow

$$I = \int j \bullet ds$$

Example: wire with constant current density $j = j_0 \cdot \hat{a}_z$

$$I = \int_{0}^{2\pi} \int_{0}^{a} j_{0} \cdot \hat{a}_{z} \bullet r \cdot dr \cdot d\varphi \cdot \hat{a}_{z} = j_{0} \cdot \pi \cdot a^{2}$$



ds , in cylindrical geometry

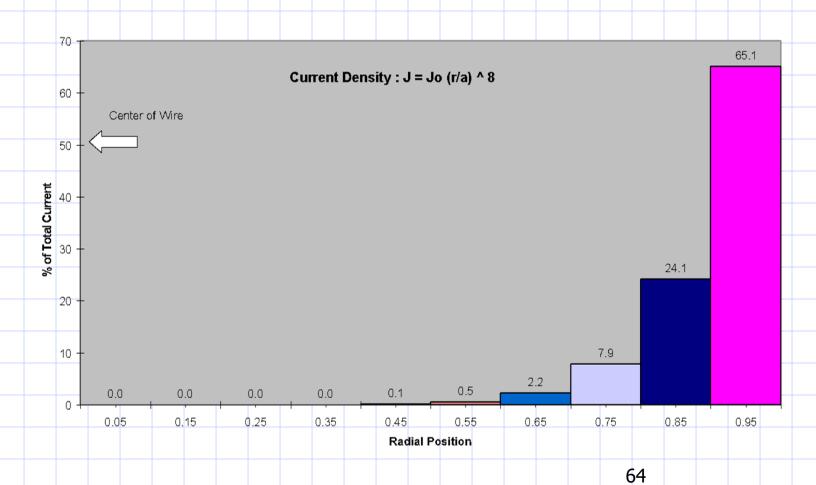
a - Find I in terms of
$$J_0$$
 for $j = j_0 \cdot \left(\frac{r}{a}\right)^{\circ} \cdot \hat{a}_z$

Peak Density

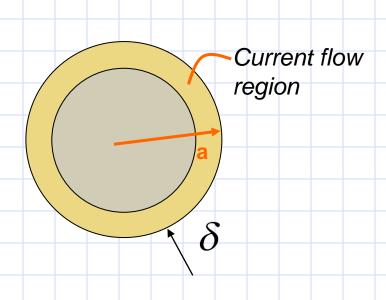
a.
$$I = \int J \cdot ds = \int_{0}^{2\pi} \int_{0}^{a} \int_{0}^{\pi} \left(\frac{c}{a}\right)^{8} r dr d\phi = \frac{2\pi J_{o}}{a^{2}} \int_{0}^{10} \int_{0}^{a} r dr d\phi = \frac{2\pi J_{o}}{a^{2}} \int_{0}^{10} \left[\frac{10}{a^{2}} \int_{0}^{a} \frac{10}{a^{2}} \int_{0}^{10} r dr d\phi = \frac{2\pi J_{o}}{a^{2}} \int_{0}^{10} \frac{10}{a^{2}} \int_{0}^{10} r dr d\phi = \frac{2\pi J_{o}}{a^{2}} \int_{0}^{10} \frac{10}{a^{2}} \int_{0}^{10} r dr d\phi = \frac{2\pi J_{o}}{a^{2}} \int_{$$

NOTE: IF CURRENT WAS DISTRIBUTED UNIFORMLY, THEN $J = \frac{I}{\pi a^2}$ Since it is concentrated a edge, the peak value (Jo) is larger.

Note that for this current distribution, there is much more current in the outer shell. This is a combination of the increased density and the larger area of each shell.



- In conductors, current tends to flow in increasingly thin surface sheets at higher frequencies (the "skin effect")
- Skin effect in a wire:



$$j = \frac{I}{Area} \cong \frac{I}{2 \cdot \pi \cdot a \cdot \delta}$$
But, $\delta \xrightarrow{\lim it} 0 \Rightarrow j \rightarrow \infty$

For high frequency, the area for resistance for a circular wire is

$$A = 2 \pi a \delta$$
 $A = 2 \pi b \delta$

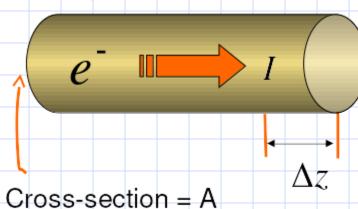
$$\mathcal{S}=$$
 1 D_s current flow current density high

We now obtain an alternate expression for current density

Wire with current, I







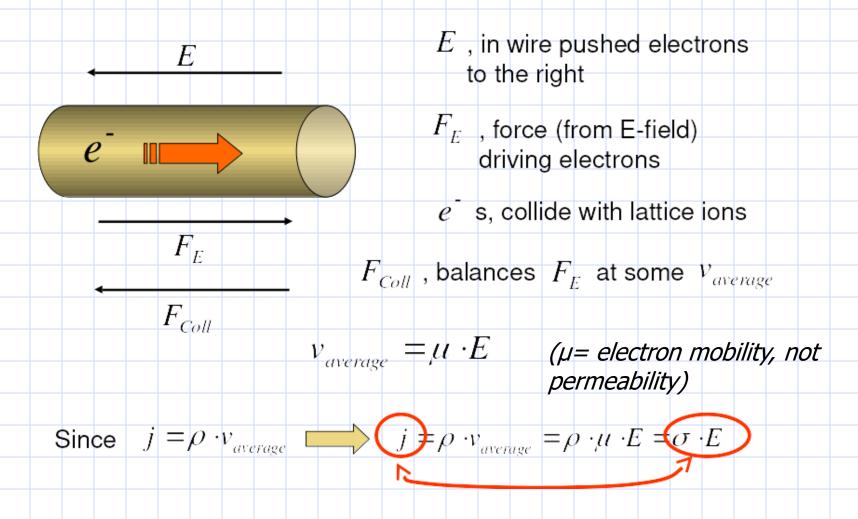
Assume all particles move at same v

• In Δt , all particles within $\Delta z = v.\Delta t$ will pass through the right face

$$\therefore \Delta Q = \rho \cdot \Delta z \cdot A = \rho \cdot v \cdot A \cdot \Delta t$$

$$\Rightarrow j = \frac{\Delta Q}{A \cdot \Delta t} = \frac{\rho \cdot v \cdot A \cdot \Delta t}{A \cdot \Delta t} = \rho \cdot v$$

$$j = \rho$$



$$j = \sigma \cdot E$$
 = Ohm's Law

Conductivity - units of S/m or 1/ohm-m

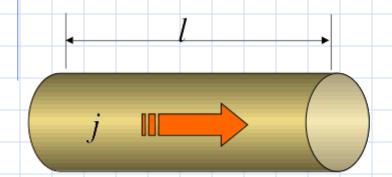
Good conductor eg. Cu

Good insulator

 $j = \sigma \cdot E$, is Fields and Waves version of Ohm's Law

Note that this violates one of our electrostatic assumptions: that the e-field will have no curl.

Resistance of a cylindrical wire:



$$I = j \cdot A = \sigma \cdot E \cdot A$$

$$V = -\int E \bullet dl = E \cdot l$$

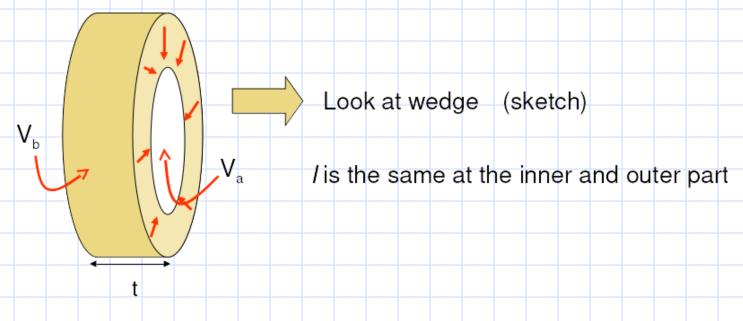
$$\frac{V}{I} = \frac{E \cdot l}{\sigma \cdot E \cdot A} = \frac{l}{\sigma \cdot A} = R$$

Do Lecture 13, Exercise 2 in groups of up to 4.

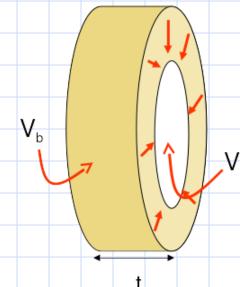
$$R = \frac{l}{\sigma \cdot A}$$
 Valid if only j and A are constant

What if they are not? Compute V and I separately and form V/I

Example: Disk with Radial Current



Current and Resistance



I is the same at the inner and outer part of disk

$$V_{a} \qquad j = \frac{I}{Area} \cdot \hat{a}_{r} = -\frac{I}{2 \cdot \pi \cdot r \cdot t} \cdot \hat{a}_{r} \qquad \text{t=thicknes}$$

$$E = \frac{j}{\sigma} = -\frac{I}{2 \cdot \pi \cdot r \cdot \sigma \cdot t} \cdot \hat{a}_{r}$$

Compute potential difference between inner and outer part of disk:

$$V_b - V_a = -\int_a^b E \bullet dl = \frac{I}{2 \cdot \pi \cdot \sigma \cdot t} \Big|_a^b \frac{dr}{r} = \frac{I}{2 \cdot \pi \cdot \sigma \cdot t} \ln \left(\frac{b}{a}\right)$$

$$\therefore R = \frac{V}{I} = \frac{\ln(b/a)}{2 \cdot \pi \cdot \sigma \cdot t}$$

Current and Resistance

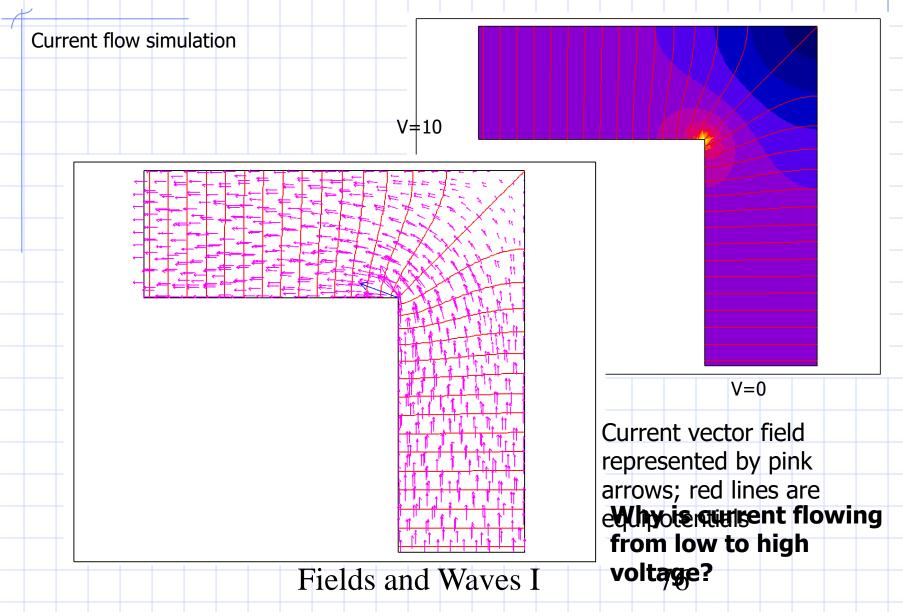
General expression of the resistance

$$R = \frac{V}{I} = \frac{\int E \cdot dl}{\int j \cdot dS} = \frac{\int j / \sigma \cdot dl}{\int j \cdot dS} = \int \frac{dl}{\sigma(l)S(l)}$$

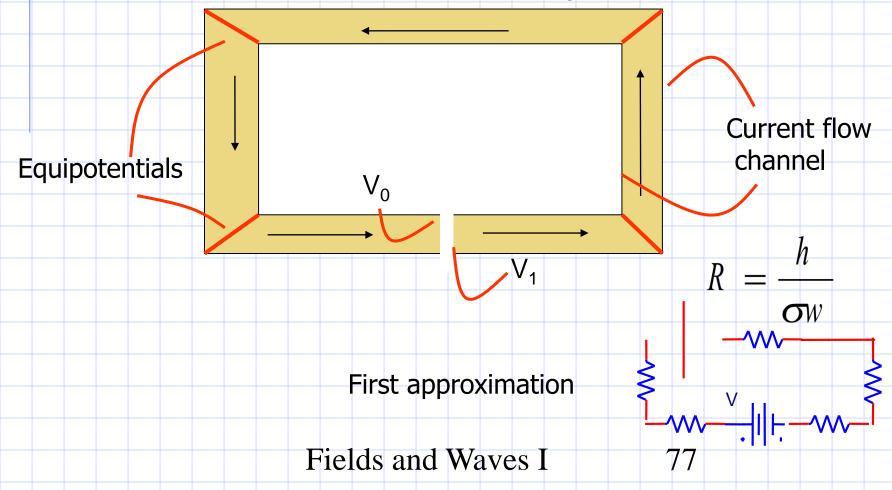
$$R = \int_{a}^{b} \frac{dr}{\sigma \cdot 2 \cdot \pi \cdot t \cdot r} = \frac{I}{2 \cdot \pi \cdot \sigma \cdot t} |_{a}^{b} \frac{dr}{r} = \frac{I}{2 \cdot \pi \cdot \sigma \cdot t} \ln \left(\frac{b}{a}\right)$$

$$V_{1}$$

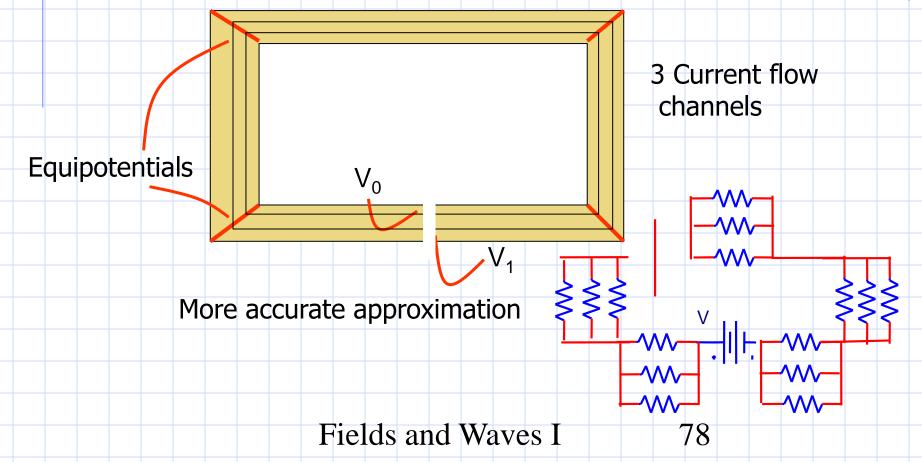
- Since current density is proportional to (and parallel to) electric field, we can represent J in finite element / finite difference analysis similarly to how we would represent E
- To address resistance, note that we are addressing the flow of electrons (current) across equipotentials.



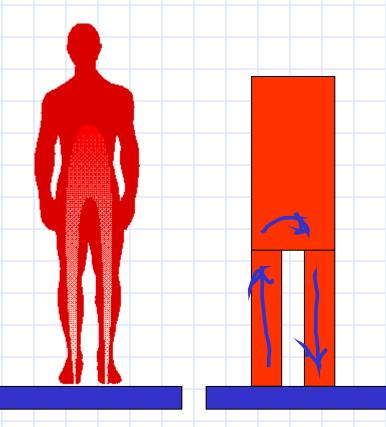
Calculation of this closed loop resistance



- More accurate calculation
 - Subdivision according to current flow



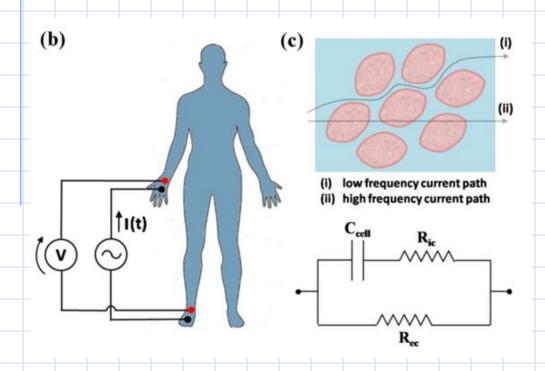
Bioelectrical Impedance Analysis



- Bioelectrical impedance analysis (BEA) is a method of electrically measuring body composition (muscle, body fat, hydration)
- Probes are used to measure the current-voltage relationship for a signal passing between to body surfaces (at left: from one foot to another)

http://www.tanita.com/en/personal

Bioelectrical Impedance Analysis

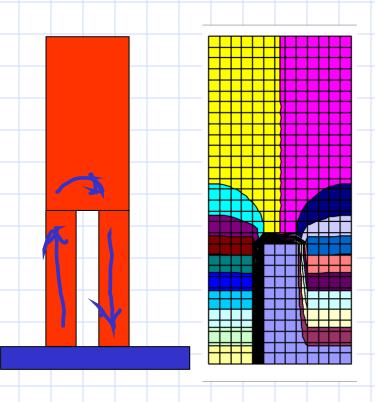


- Different cells have different impedances
- For instance, a fat cell has a much higher impedance than a muscle cell

Grossi 2017

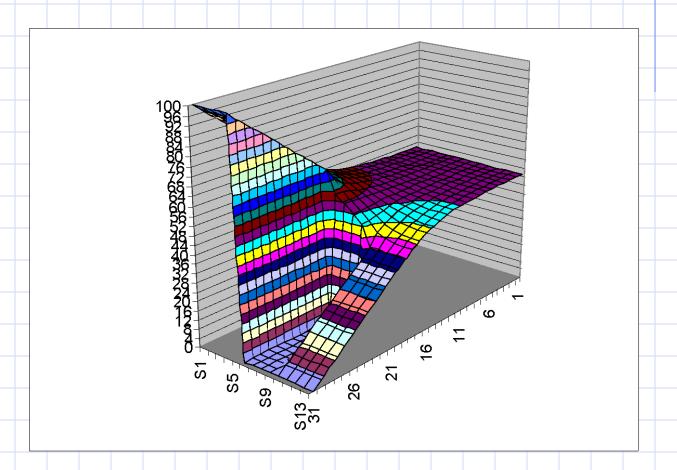
Bioelectrical Impedance Analysis

- Laplace/Poisson's Equation finite difference methods could be employed to create an equipotential map of the body
- Laplace's equation would be used since the body is presumed not to have free charge
- Dirichlet boundary conditions: electric potential is defined at either foot



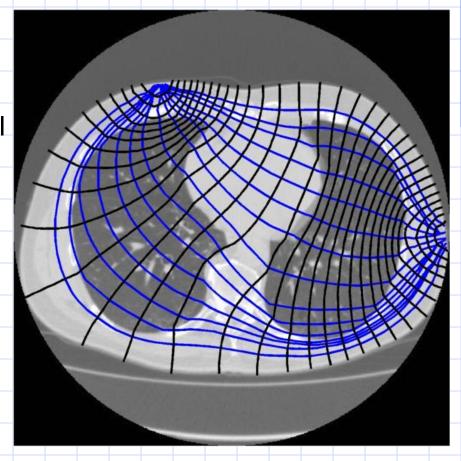
Bioelectrical Impedance Analysis

Legs dominate the resistance.



Electrical Impedance Tomography

- Small signals applied to the body's surface with electrodes will allow field and equipotenial lines to be mapped inside the body
- Using image construction algorithms, an 3D image of tissues can be created



Wikipedia

• Who can tell me (without looking it up) what a theremin is?

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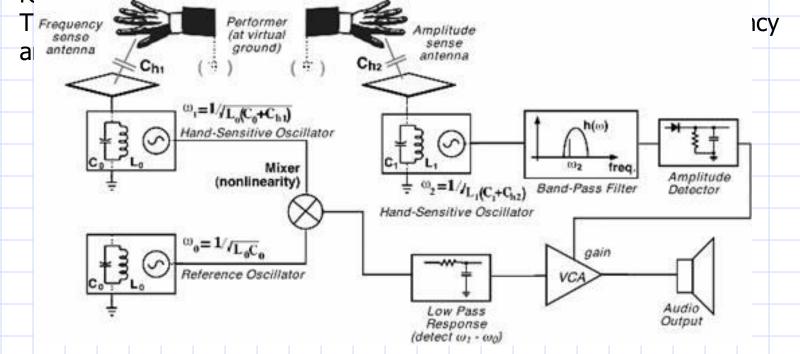


- A theremin is an analog electronic instrument based on LRC oscillation
- Invented by Soviet inventor
 Leon Theremin in 1920 as an
 offshoot of research on
 proximity sensors
- First instrument that could be played without physical contact
- One of the first electronic instruments



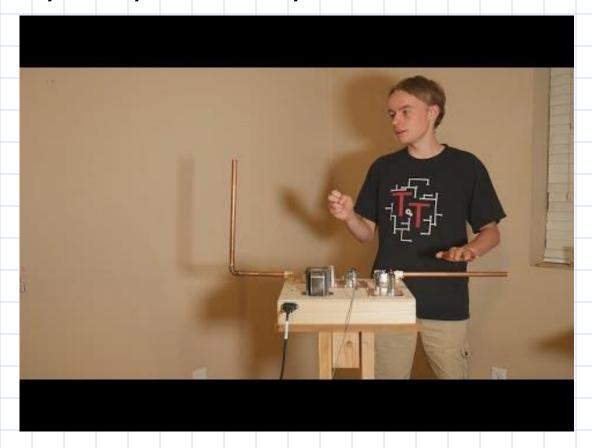
Wikipedia

- Two high-frequency (100+ kHz LC oscillator circuits) have their output voltages added together
- One includes an antenna that interacts capacitively with the performer's hand; capacitance varies slightly as their hand moves
- Small variation in capacitance leads to a beat frequency with the reference oscillator



http://asmir.info/

Built by many DIY hobbyists



Wrap-Up

- Quiz 2 will be next week and will cover Unit 2 skills.
 Today is the last lecture that will be covered under Quiz 2.
- Quiz 2 review materials will be released this weekend.
- Skill retests for this week:

1e, 1f 1h, 1i, 1j